

NE/SE522

High-Speed Dual-Differential Comparator/Sense Amp

Product Specification

Linear Products

FEATURES

- 15ns maximum guaranteed propagation delay
- 20 μ A maximum input bias current
- TTL-compatible strobes and outputs
- Large common-mode input voltage range
- Operates from standard supply voltages

APPLICATIONS

- MOS memory sense amp
- A-to-D conversion
- High-speed line receiver

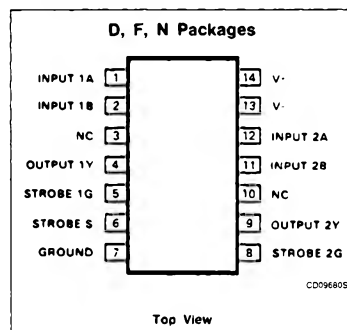
ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE
14-Pin Cerdip	0 to 70°C	NE522F
14-Pin Cerdip	-55°C to 125°C	SE522F
14-Pin Plastic DIP	0 to +70°C	NE522N
14-Pin Plastic SO	0 to 70°C	NE522D

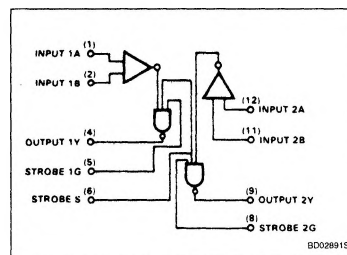
ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V+	Supply voltage Positive	+7	V
V-	Supply voltage Negative	-7	V
V _{IDR}	Differential input voltage	± 6	V
V _{IN}	Input voltage Common-mode Strobe/gate	± 5 +5.25	V
P _D	Power dissipation	600	mW
T _A	Operating temperature range NE522 SE522	0 to 70 -55 to +125	°C
T _{STG}	Storage temperature range	-65 to +150	°C
T _{SOLD}	Lead soldering temperature (10sec max)	+300	°C

PIN CONFIGURATION



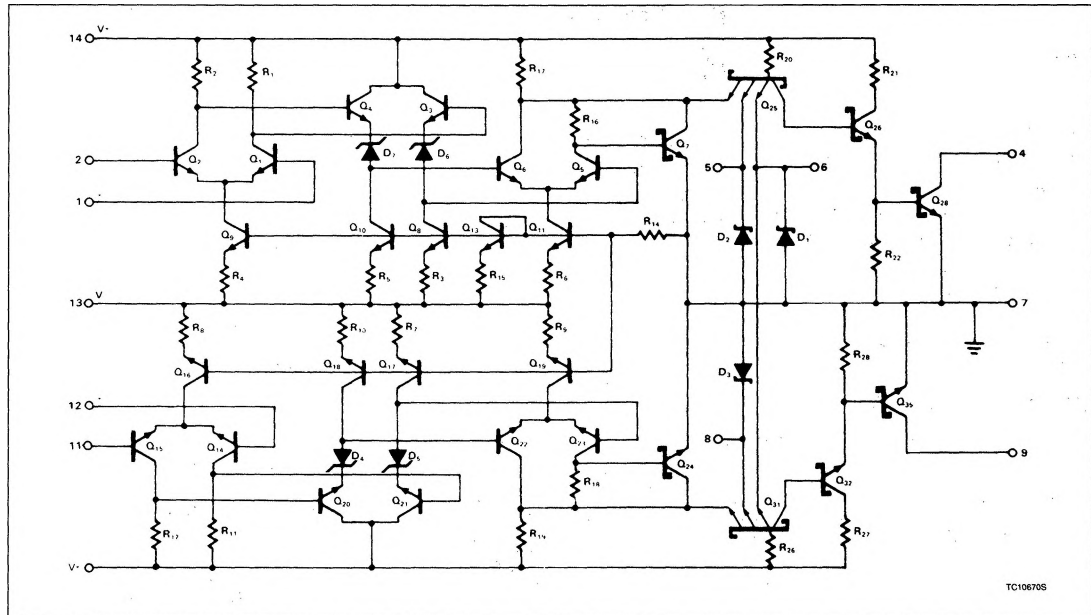
BLOCK DIAGRAM



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EQUIVALENT SCHEMATIC



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DC ELECTRICAL CHARACTERISTICS (SE522) $\pm 5V \pm 10\%$, $T_A = -55$ to $+125^\circ\text{C}$, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Min	Typ	Max	
V_{OS}	Input offset voltage At 25°C Over temperature range	$V_+ = +4.5V$, $V_- = -4.5V$		6	7.5 15	mV
I_{BIAS}	Input bias current At 25°C Over temperature range	$V_+ = +5.5V$, $V_- = -5.5V$		7.5	20 40	μA
I_{OS}	Input offset current At 25°C Over temperature range	$V_+ = +5.5V$, $V_- = -5.5V$		1.0	5 12	μA
V_{CM}	Common-mode voltage range	$V_+ = +4.5V$, $V_- = -4.5V$	± 3			V
V_{IL}	Low level input Voltage at 25°C Over temperature				0.8 0.7	V
V_{IH}	High level input		2.0			V
I_{IH}	Input current High	$V_+ = +5.5V$, $V_- = -5.5V$ $V_{IH} = 2.7V$ 1G or 2G strobe Common strobe S			50 100	μA μA
I_{IL}	Low input current	$V_{IL} = 0.5V$ 1G 2G strobe Common strobe S			-2 -4	mA mA
V_{OL}	Output voltage Low	$V_+ = +4.5V$, $V_- = -4.5V$ $I_{OL} = 20\text{mA}$, $T_A = 25^\circ\text{C}$ $I_{OL} = 10\text{mA}$			0.5 0.5	V
I_{OH}	Output current High	$V_{CC+} = +4.5$, $V_{CC-} = -4.5V$, $V_{OH} = 5.5V$			250	μA
V_+ V_-	Supply voltage Positive Negative		4.5 -4.5	5.0 -5.0	5.5 -5.5	V
I_{CC+} I_{CC-}	Supply current Positive Negative	$V_+ = 5.5V$, $V_- = -5.5V$, $T_A = 25^\circ\text{C}$		27 -15	35 -28	mA

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DC ELECTRICAL CHARACTERISTICS (NE522) $\pm 5V \pm 5\%$, $T_A = 0$ to $+70^\circ\text{C}$, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Min	Typ	Max	
V_{OS}	Input offset voltage At 25°C Over temperature range	$V_+ = +4.75V$, $V_- = -4.75V$		6	7.5 10	mV
I_{BIAS}	Input bias current At 25°C Over temperature range	$V_+ = +5.25V$, $V_- = -5.25V$		7.5	20 40	μA
I_{OS}	Input offset current At 25°C Over temperature range	$V_+ = +5.25V$, $V_- = -5.25V$		1.0	5 12	μA
V_{CM}	Common-mode voltage range	$V_+ = +4.75V$, $V_- = -4.75V$	± 3			V
I_{IH}	Input current High	$V_+ = +5.25V$, $V_- = -5.25V$ $V_{IH} = 2.7V$ 1G or 2G strobe Common strobe S			50 100	μA μA
I_{IL}	Low	$V_{IL} = 0.5V$ 1G 2G strobe Common strobe S			-2.0 -4.0	mA mA
V_{OL}	Output voltage low	$V_+ = +5.25V$, $V_- = -5.25V$, $V_{I(S)} = 2.0V$ $I_{LOAD} = 20\text{mA}$			0.5	V
I_{OH}	Output current high High	$V_{CC+} = +4.75$ $V_{CC-} = -4.75V$, $V_{OH} = 5.25V$			250	μA
V_+ V_-	Supply Voltage Positive Negative		4.75 -4.75	5.0 -5.0	5.25 -5.25	V
I_{CC+} I_{CC-}	Supply current Positive Negative	$V_+ = 5.25V$, $V_- = -5.25V$, $T_A = 25^\circ\text{C}$		27 -15	35 -28	mA

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AC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $R_L = 280\Omega$, $C_L = 15\text{pF}$

SYMBOL	PARAMETER	FROM INPUT	TO OUTPUT	LIMITS			UNIT
				Min	Typ	Max	
I_R	Input resistance				4		$k\Omega$
I_C	Input capacitance				3		pF
Large-signal switching speed							
$t_{PLH(D)}$	Propagation delay Low to high ¹	Amp	Output		10	15	ns
$t_{PHL(D)}$	High to low ¹	Amp	Output		8	12	
$t_{PLH(S)}$	Low to high ²	Strobe	Output		6	13	
$t_{PHL(S)}$	High to low ²	Strobe	Output		5	9	
f_{MAX}	Maximum operating frequency			25	35		MHz

NOTES:

- Response time measured from 0V point of $\pm 100\text{mV}_{p,p}$ 10MHz square wave to the 1.5V point of the output.
- Response time measured from 1.5V point of the input to 1.5V point of the output.

LOGIC FUNCTION TABLE

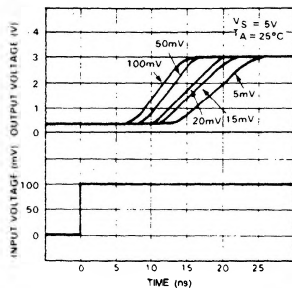
V_{ID} (A^+ , B^-)	STRS	STRG	Output Transistor
$< -V_{OS}$	H	H	ON
$-V_{OS} < V_{ID} < V_{OS}$	H	H	Undefined
$> V_{OS}$	H	H	OFF
X	L	X	OFF
X	X	L	OFF

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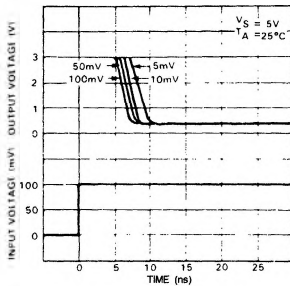
TYPICAL PERFORMANCE CHARACTERISTICS

Response Time for Various Input Overdrives



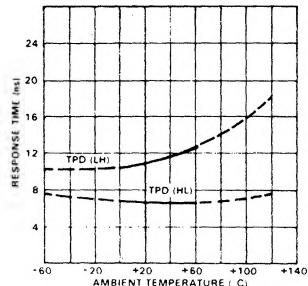
QP067015

Response Time for Various Input Overdrives



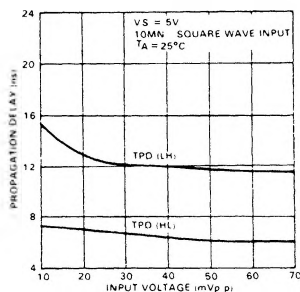
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Response Time vs Temperature



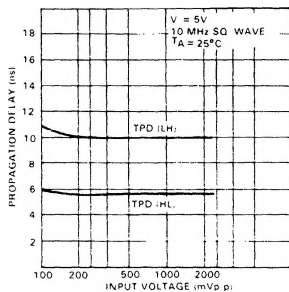
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Propagation Delay for Various Input Voltages



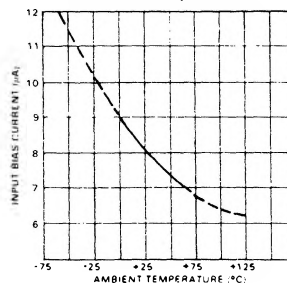
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Propagation Delay for Various Input Voltages



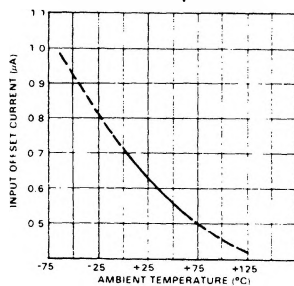
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Input Bias Current vs Ambient Temperature



QP067515

Input Offset Current vs Ambient Temperature



QP067615